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Porous wide band gap BiNbO<sub>4</sub> ceramic nanopowder synthesised by low temperature solution-based method for gas sensing applications

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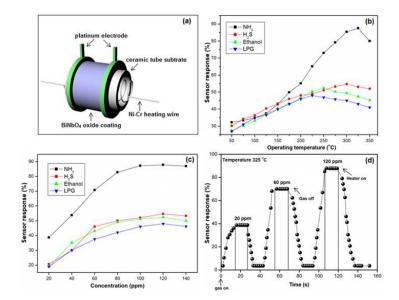
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# **Graphical Abstract**



Abstract

In this study, we report the gas sensing behavior of BiNbO<sub>4</sub> nanopowder prepared by low temperature simple solution-based method. Before sensing behaviour study, the as-synthesized nanopowder was characterized by X-ray diffraction, scanning electron microscopy, transmission electron microscopy, UV–diffuse reflectance spectroscopy, impedance analysis, and surface area measurement. The NH<sub>3</sub> sensing behavior of BiNbO<sub>4</sub> was then studied by temperature modulation (50-350 °C) as well as concentration modulation (20-140 ppm). At the optimum operating temperature of 325 °C, the sensitivity was measured to be 90%. The cross-sensitivity of assynthesized BiNbO<sub>4</sub> sensor was also investigated by performing sensing behavior of other gases such as hydrogen sulphide (H<sub>2</sub>S), ethanol (C<sub>2</sub>H<sub>5</sub>OH), and liquid petroleum gas (LPG). Finally, selectivity of the sensing material toward NH<sub>3</sub> was characterized by observing the sensor response with gas concentrations in the range 20–140 ppm. The response and recovery time for NH<sub>3</sub> sensing at120 ppm were about16 s and about17 s, respectively.

Keywords: BiNbO<sub>4</sub>; gas sensor; wide band gap ceramic; p-type semiconductor.

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# Introduction

ABO<sub>4</sub> compounds (A = Bi<sup>3+</sup> or Sb<sup>3+</sup> and B = Nb<sup>5+</sup>, Ta<sup>5+</sup> or Sb<sup>5+</sup>) have received much attention owing to their unique properties such as ferroelectrics and anti-ferroelectrics with the stibiotantalite structure, consisting of a layer of vertex sharing and distorted BO<sub>6</sub> octahedral parallel to the (001) plane of the orthorhombic unit cell. Moreover, they possess excellent piezoelectric, pyroelectric, and electro-optic properties at room temperature [1]. Among the various ABO<sub>4</sub> compounds, bismuth-based microwave dielectric ceramic has stimulated significant research interest owing to its unique structural characteristics, electrical properties and promising applications in the field of multilayer capacitors [2–4]. From the viewpoint of gas sensor applications, BiNbO<sub>4</sub> could be considered as a promising candidate for future developments of sensing materials. According to the sensing mechanisms of conductance-based gas sensors, the overall sensing performance is determined by the charge transfer between the adsorbed species and the sensing material [5]. With the progress of gas sensing research, porous structure with a high specific surface area and an easy surface accessibility has been found to significantly improve the gas sensing properties. Until now, BiNbO<sub>4</sub> materials are generally synthesized by solid-state processes, which are quite strenuous and require high reaction temperature. The high operating temperature in material preparation leads to large agglomerations of particles and low surface area which results in to their poor gas sensing behavior.

Ammonia (NH<sub>3</sub>) is one of the most used gases in many chemical industries, agricultural industries including fertilizer factories, food industries petroleum industries, rubber industries, lather industries as well as industrial refrigeration systems [6]. Ammonia also contributes

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significantly to the nutritional needs of terrestrial organisms by serving as a precursor of food and fertilizers. It is also a building block for the synthesis of many pharmaceuticals. Despite its usefulness, NH<sub>3</sub> is both caustic and hazardous to humans, especially when its concentration exceeds threshold value (TLV) of 25 ppm [7]. Its exposure may develop a burning sensation in eyes, nose, and throat. The Permissible exposure limits (PELs) set by Occupational safety and health administration (OSHA), USA – is around 50 ppm. To prevent the serious accidents caused by the NH<sub>3</sub> gas leakage, the compact NH<sub>3</sub>-sensing devices that can be placed on various emitting sites are required. Although, there are ample reports published on NH<sub>3</sub> sensing, novel materials are explored every day in order to obtain better sensing performance.

In the present paper, we are reporting  $NH_3$  sensing behavior of novel material-BiNbO<sub>4</sub> nanopowder. To the best of our knowledge, the detailed gas sensing behaviour of porous BiNbO<sub>4</sub> nanostructures prepared by a chemical-based method is not reported yet. The sensing response of BiNbO<sub>4</sub>-based material was studied by variation in its electrical resistance in the air and reducing gas environments. The change in resistance is caused by the transfer of charges as a result of adsorption between gas molecules and the metal oxide semiconductor surface. The BiNbO<sub>4</sub> nanopowder-based sensor realizes the selective detection of  $NH_3$  to other interference gases such as  $H_2S$ , ethanol and LPG.

# • Preparation of BiNbO<sub>4</sub> nanopowder

A simple yet reliable and safer chemical-based procedure was employed for the synthesis of BiNbO<sub>4</sub> nanopowder using common reagents like bismuth nitrate, niobium ammonium oxalate, tartaric acid. All the reagents used in the experiments are analytically pure which ensures high

purity BiNbO<sub>4</sub> nanopowder. Hydrated niobium was formed by the dissolution of the niobium ammonium oxalate in water and precipitated as niobium hydroxide by adding ammonium hydroxide. The resulting precipitate was washed using distilled water and dried; the prepared niobium hydroxide was then assyaed at 1,200 °C for 2 h to estimate the amount of niobium oxide present in the niobium hydroxide. The required amount of niobium hydroxide was dissolved in an aqueous tartaric acid [TA, HO<sub>2</sub>CCH(OH)CH(OH)CO<sub>2</sub>H] solution in TA to Nb ratio of 2:1. Then, a stoichiometric ratio of bismuth nitrate was added to this precursor mixture with a Bi to Nb ratio of 1:1, followed by drop wise addition of 0.2 M PVA solution and 0.1 M ethylene glycol solutions with constant stirring, and the pH value of the final solution was adjusted to 7 using  $NH_4OH$  solution. The resulting solution was heated on a hot plate, and after the complete gelation, hot plate temperature was increased to 250 °C to obtain dried black fluffy mass. The porous BiNbO<sub>4</sub> nanopowder was successfully obtained by the calcination of the BiNbO<sub>4</sub> precursor at 500 °C in a muffle furnace for 2 h. Thermal behavior of the dried precursor was studied in the air atmosphere by TG/DTA using a Pyris Diamond thermal gravimetric analyzer. The calcined sample is characterized by X-ray powder diffraction using CuKa sources (XRD, X'Pert pro), scanning electron microscopy (FE-SEM, JSM-7500F), transmission electron microscopy (TEM, JEOL JEM-2100F), Brunauer-Emmett-Teller surface area measurement (BET, Micrometritics, ASAP 2020), UV-vis diffuse reflectance spectroscopy (DRS, Varian-Cary 5000) and impedance analysis (Model-micro auto lab type III), respectively.

• Results and discussion

Figure 1a shows the simultaneous TGA and DTA plots for the dried precursor. As per TGA data, the total weight loss is around 35% over a temperature range of room temperature to 900 °C.

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The endothermic (negative) peak on the DTA curves centered at 128 °C, with drastic weight loss in the TG curve, corresponds to the evaporation of residual water and chemically bound water in the precursor sample. As the process of heating is continued, two distinguishable exothermic transformations observed at 344 and 421 °C. This might be due to the reaction of nitrates with tartaric acid and decomposition of remaining organic constituents in the precursor. In order to obtain the orthorhombic phase of the powder, the calcination condition was optimized to be 500 °C for 3 h. Figure 1b shows the XRD pattern of calcinated BiNbO<sub>4</sub> powder. It can be seen that all the peaks in the XRD spectrum perfectly indexed according to the orthorhombic phase of BiNbO<sub>4</sub> with lattice constants a, b, and c of 4.979, 11.68, and 5.674Å (JCPDS 16-0295). The optimized calcination temperature to obtain pure orthorhombic BiNbO<sub>4</sub> was considerably lower compared to all the previous reports [1, 3, 8, and 9]. From the Scherrer equation, the average crystallite size of BiNbO<sub>4</sub> was calculated to be 23 nm.

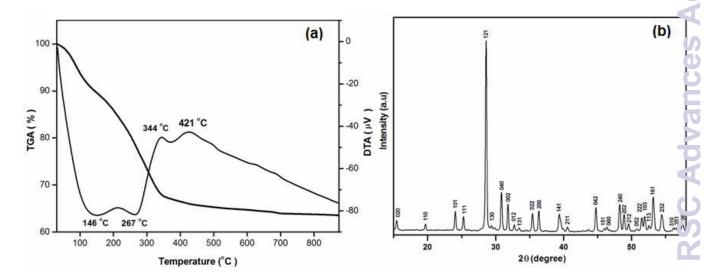


Figure 1. Simultaneous TG/DTA plots obtained for the BiNbO<sub>4</sub> precursor sample (a) and XRD pattern of BiNbO<sub>4</sub> precursor powder calcined at 500 °C for 3h.

The FE-SEM image clearly shows the porous morphology of the as-synthesized product (Fig. 2a). The porous morphology facilitates analyte gas to diffuse easily toward the entire surface of the material and improves surface interactions. This, in turn, improves the rate of reaction of gas molecules with the adsorbed oxygen on the surface. The TEM image of BiNbO<sub>4</sub> nanopowder (Fig. 2b) indicates the formation of well-dispersed spherical shape particles with an average diameter of ~30 nm. The specific surface area (41.27 m<sup>2</sup>/g) of calcinated BiNbO<sub>4</sub> nanopowder was estimated by the BET method.

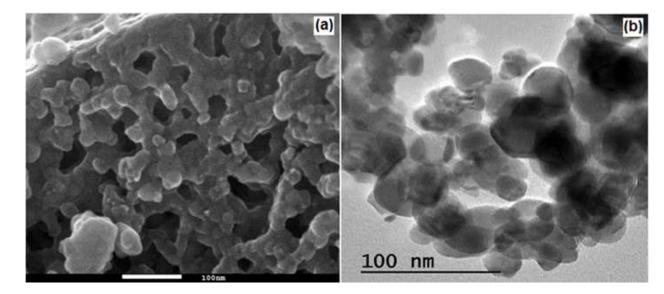


Figure 2. FE-SEM images of BiNbO<sub>4</sub> (a) and HR-TEM micrograph of BiNbO<sub>4</sub> (b).

The porosity of the synthesized BiNbO<sub>4</sub> nanopowder was also studied by mixing nanopowder with a few drops of polyvinyl alcohol solution. The mixture was pressed into a pellet and then heat-treated at 400 °C to remove the residual polymer. The porosity was calculated by using the following relation [10]:

$$P = l - (d/dx) \tag{1}$$

Where *d* is m/V calculated from the dimensions and mass of the pellet. X-ray density (dx) was calculated using the following equation:

$$dx = 8M/Na^3 \tag{2}$$

where M, N, and a are the molecular weight, Avogadro's number ( $6.023 \times 10^{23}$  atoms/mole), and lattice constant, respectively. The porosity of the sample was 57%, leading to the adsorption of gas molecules in the pores yielding a highly sensitive material.

The UV-vis absorption spectrum of the products is shown in Fig. 3a. The band gap of the sample can be calculated by the following equation:  $(\alpha h v)^2 = B \times (h v - E_g)$  where  $\alpha$  is the absorption coefficient, hv is the photon energy, B is a constant, and  $E_g$  is the band gap. The  $(\alpha h v)^2$  vs. hv curve is also shown in Fig. 3b. Extrapolation of the linear portion of the energy axis at  $(\alpha h v)^2 = 0$  gave the  $E_g$  value of 3.2 eV. The electrical conductivity of BiNbO<sub>4</sub> was evaluated from complex impedance spectra (Fig. 3c) and expressed as a function of temperature from 30 to 175 °C in dry air. The resistance R of the sample was obtained from the intercept on the *x*-axis of the complex impedance plot. The Arrhenius plot (Fig. 3d) shows that the observed temperature dependence on electrical conductivity is similar to those observed in semiconductor oxide systems. The activation energy of the conduction process was calculated from the slope of log  $\sigma$  vs. 1/T plot. In the temperature range of 30-175 °C, the activation energy of BiNbO<sub>4</sub> was 0.29 eV.

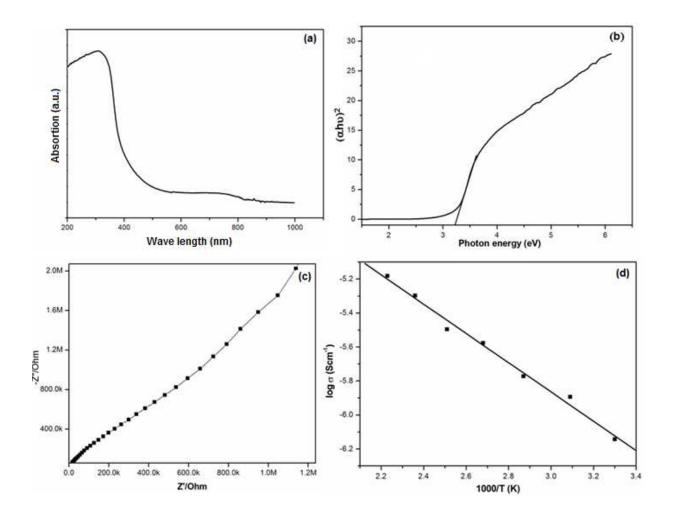


Figure 3. Experimental results of UV–vis DRS (a),  $(\alpha hv)^2$  vs. hv cures (b), impedance spectrum (c), and the Arrhenius plot of BiNbO<sub>4</sub>nanopowder (d).

For gas sensing measurement, the prepared BiNbO<sub>4</sub> nanopowder was mixed with  $\alpha$ terpineol to form a paste and then coated on an Al<sub>2</sub>O<sub>3</sub> ceramic tube with a pair of platinum electrode on each end. In order to provide required operating temperature while gas sensing, a small nichrome (NiCr) alloy coil was placed inside the tube to function as a heater. The schematic of a sensor element used for the gas response studies is shown in Fig. 4(a). A detailed

description of the sensor device, electrical circuit, and preparation method can be followed from **RSC Advances Accepted Manuscript** 

our previous report [11]. The brief sensing analysis with the sensing element is as follows. In the first step, the resistivity of the sample was measured in the air  $(R_a)$ , i.e., prior to admitting test gas inside the sealed chamber as well as in the presence of a test gas  $(R_g)$ . It was observed that the BiNbO<sub>4</sub> nanopowder-based sensor offered an increased resistance in the presence of reducing gases. This behavior exhibits p-type semiconductor nature for the BiNbO<sub>4</sub> nanopowder. The sensitivity of the sensors S was calculated using the following mathematical expression: S = $R_a/R_g$  [12]. Figure 4(b) shows the dynamic gas sensing characteristics of BiNbO<sub>4</sub> nanopowder towards NH<sub>3</sub>, H<sub>2</sub>S, ethanol, and LPG as a function of operating temperatures. Among these gases, NH<sub>3</sub> is the main test gas whereas the other the response of other gas is analyzed in order to observe the cross-sensitivity effect. Here, the response was defined as the change in resistance before and after the admittance of reducing gas. In order to obtain the optimum operating temperature (T<sub>opt</sub>) for NH<sub>3</sub>, the sensor response was analyzed over a temperature range of 50-350 °C keeping the gas concentration constant. This analysis was term as temperature modulation study. The T<sub>opt</sub> for NH<sub>3</sub> sensing was found at the temperature of about 325 °C. The T<sub>opt</sub> for H<sub>2</sub>S (54%), ethanol (46%) and LPG (40%) sensing was around 300, 250, and 225 °C, respectively. The behavior of sensor in varying gas concentration is also an important analysis. It gives the linear working range, in terms of concentration, of a sensor. This study can be termed as concentration modulation. The gas sensing response of BiNbO<sub>4</sub> as a function of concentrations (20-140 ppm) of test gases at their Topt(NH3-325 °C, H2S-305 °C, ethanol-250 °C, and LPG-225 °C) is shown in Fig. 4(c). The sensor response was remarkably high when exposed to NH<sub>3</sub> at its T<sub>opt</sub> (i.e., 325 °C) compared to the sensor response of other gases at their respective

 $T_{opt}s$ . The lower sensor response of other test gases (such as H<sub>2</sub>S, ethanol, and LPG) even at their own  $T_{opt}s$  clearly indicates a selective response of the sensor towards ammonia. This selective response was owing to the complete oxidization of NH<sub>3</sub> on the sensor surface, thereby changing the conductivity of the sensor element drastically compared to other gases.

Figure 4(d) shows the response variations in the BiNbO<sub>4</sub> sensor upon exposure to  $NH_3$ gas injection and refreshing. The measurements were performed by injecting varying amounts of NH<sub>3</sub> gas into the sealed chamber, followed by refreshing (i.e., stopping gas injection and flushing of residual gases) at 325 °C. The measured response for 20, 60, and 120 ppm NH<sub>3</sub> gas was ~38%, 70%, and 87%, respectively. The NH<sub>3</sub> gas attained maximum response within 16 s, and its recovery time was less than 17 s. The fast response as well as recovery of the above discussed sensor can be attributed to the large surface area of the material and rapid adsorption/desorption rate due to smaller molecular weight of NH<sub>3</sub> compared to other gases such as hydrocarbon gases. The relatively fast response is consistent with the hypothesis of a surface effect, especially related to the ammonia adsorption on the BiNbO4 surface and can be correlated to the surface morphology. High porosity increases the number of accessible sites for the adsorption of molecules, resulting in a high response to NH<sub>3</sub>. The electric dipole moment of ammonia is  $5.0 \times$  $10^{-30}$  C·m, and this high polarity would easily attract the metal oxide-based positively charged nanoparticles. In addition, response properties and selectivity depend on the nature of active sites in structure of the sensor surface. Moreover, surface acidity of metal oxides may play an important role in selective sensing of NH<sub>3</sub>. Taking into account the fact that NH<sub>3</sub> is a basic molecule, the result can be explained as follows. The surface of the oxides with more electronegative metal (i.e., more acidic (Nb)) strongly interacts with basic NH<sub>3</sub> molecules,

resulting in high response to NH<sub>3</sub>. The high sensitivity and the low detection level of the sensor are very interesting points for its practical applications. Moreover, it can detect a large range of ammonia concentrations. The proposed BiNbO<sub>4</sub>–based gas sensor exhibited improved selectivity compared to the other metal oxide type NH<sub>3</sub> gas sensors. The improved selectivity obtained with the BiNbO<sub>4</sub> sensor makes it a valuable tool in the determination of NH<sub>3</sub> gas concentrations. Considering the wide use of ammonia, this sensor can be utilized in the analysis of food and beverage products, industrial refrigerant, and in the selective determination of NH<sub>3</sub> levels in the various sites such as nitrogenous fertilizers as well as other industries having typically higher concentration of other interfering gases (H<sub>2</sub>S, ethanol, and LPG). A comparison between the NH<sub>3</sub> sensing performances of the BiNbO<sub>4</sub> sensor and literature reports is summarized in Table.1. BiNbO<sub>4</sub> sensor for detection of ammonia gas shows the better detection limits than previously reported devices.

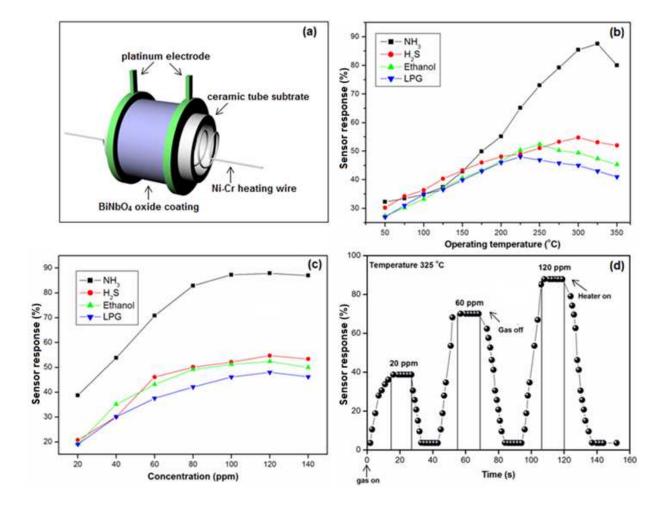


Figure 4. (a) Schematic of sensor element used for the gas response studies, (b) dynamic gas sensing characteristics of BiNbO<sub>4</sub> nanopowder towards NH<sub>3</sub>, H<sub>2</sub>S, ethanol, and LPG as a function of operating temperatures, (c) gas sensing response of BiNbO<sub>4</sub> as a function of concentrations (20–140 ppm) and (d) response and recovery time of the sensor to different concentrations of NH<sub>3</sub>.

Tabel.1
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Material	NH <sub>3</sub> concentration (ppm)	Sensor response	Response & recovery time	Reference
Pd-LaCo <sub>0.8</sub> Fe <sub>0.2</sub> O <sub>3</sub>	200	97 (300 °C)	8-20s	[13]
Zr and CoWO <sub>4</sub>	1,000	50 (700 °C)	1-3s	[14]
Pt-WO <sub>3</sub>	4,000	45 (350 °C)	1m-5mintes	[15]
Co <sub>0.8</sub> Ni <sub>0.2</sub> Fe <sub>2</sub> O	250	68 (250 °C)	20-70s	[16]
CuNb <sub>2</sub> O <sub>6</sub>	500	56 (300 °C)	15-25s	[17]
WO <sub>3</sub> nano particle	500ppb	66 (300 °C)	18-15mintes	[18]
Carbon nanotube	14 to 900	75(900ppm at room	30 to50/200 to500s	[19]
coated with Co		temperature)		
BiNbO <sub>4</sub>	120	87 (325 °C)	16-17s	Thiswork

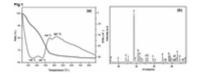
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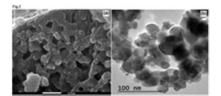
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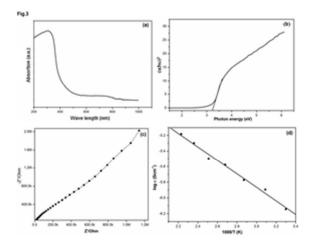
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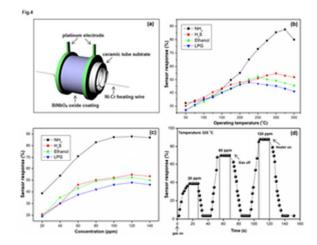
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